

Features

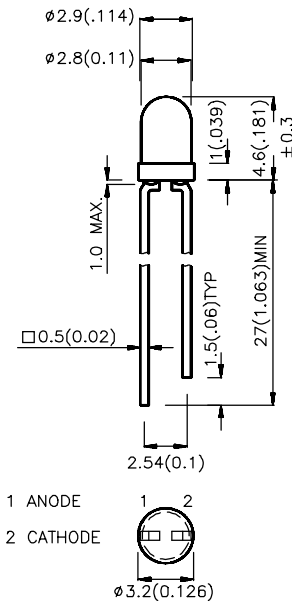
- ULTRA BRIGHTNESS.
- OUTSTANDING MATERIAL EFFICIENCY.
- RELIABLE AND RUGGED.
- IC COMPATIBLE/LOW CURRENT CAPABILITY.

L7104VGC/E

Description

The Green source color devices are made with
DH InGaN on GaAs substrate Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subjected to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 20 mA		Viewing Angle
			Min.	Typ.	2 θ 1/2
L7104VGC/E	GREEN (InGaN)	WATER CLEAR	1500	2000	34°

Note:

1. θ 1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at T_A=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_D	Dominate Wavelength	Green	565		nm	I _F =20mA
$\Delta\lambda_{1/2}$	Spectral Line Halfwidth	Green	36		nm	I _F =20mA
V _F	Forward Voltage	Green	3.9	4.5	V	I _F =20mA
C	Capacitance	Green	50		pF	V _F =0V;f=1MHz
I _R	Reverse Current	All		10	uA	V _R = 5V

Absolute Maximum Ratings at T_A=25°C

Parameter	Green	Units
Power dissipation	105	mW
DC Forward Current	30	mA
Peak Forward Current [1]	150	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Soldering Temperature [2]	260 °C For 5 Seconds	

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 4mm below package base.

Green L7104VGC/E

